Optical Properties of Pd and PdO films exposed to hydrogen\textsuperscript{1}

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In this work transmittance spectroscopy measurements in the optical/NIR range of thin films of Pd/quartz and PdO/quartz are shown. This property is monitored as a function of time upon hydrogenation. Semiconductive PdO films gradually reduce into metallic Pd when exposed to hydrogen, as confirmed by XRD, showing no appreciable shift of the bandgap during the process. The transmittance of Pd films increases by \( \sim 30\% \) in this spectral range for pressures of \( \sim 40 \) torr of hydrogen, the increase peaking at about 730nm. The transmittance measurements seem to be a very simple and fast method for monitoring this kind of systems.

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